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(71) Applicant: MICRON TECHNOLOGY, INC. [US/US]; 8000 S. Federal Way, Boise, ID 83707-0006 (US).

(72) Inventors: CAMPBELL, Kristy, A.; 9845 W. Mossy Cup Street, Boise, ID 83709 (US). MOORE, John; 12530 W. Lexus Court, Boise, Idaho 83713 (US).

(74) Agent: D'AMICO, Thomas, J.; Dickstein Shapiro Morin & Oshinsky LLP, 2101 L Street, NW, Washington, DC 20037-1526 (US).

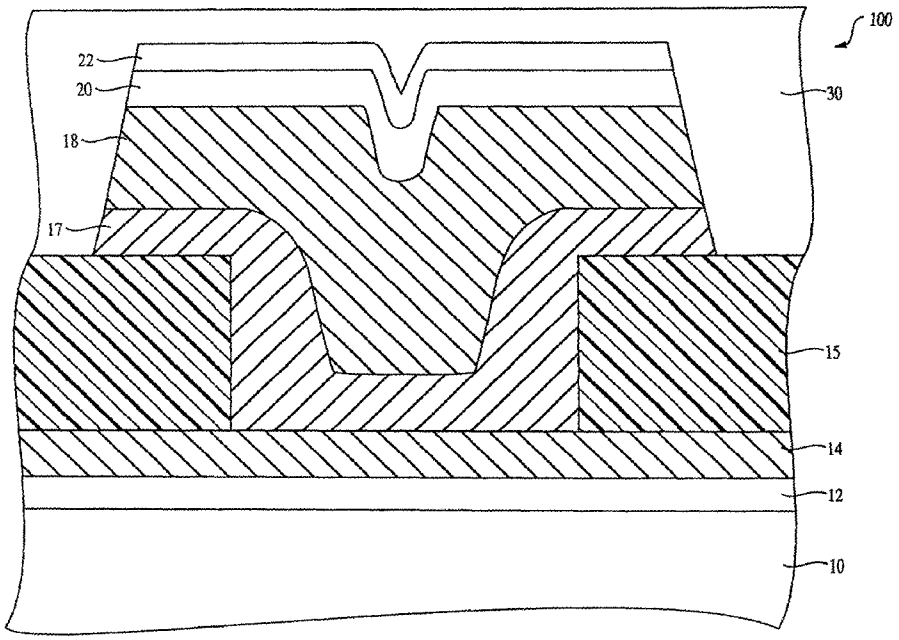
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(54) Title: SILVER-SELENIDE/CHALCOGENIDE GLASS STACK FOR RESISTANCE VARIABLE MEMORY



(57) Abstract: The invention is related to methods and apparatus for providing a resistance variable memory element with improved data retention and switching characteristics. According to an embodiment of the invention a resistance variable memory element is provided having at least one silver-selenide layer in between glass layers, wherein at least one of the glass layers is a chalcogenide glass, preferably having a Ge_xSe_{100-x} composition.

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